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CRYSTAL GROWTH

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and Crystal Technologies

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Contents

The 5th Asia Conference on Crystal Growth and Crystal Technologies

The 5th Asia Conference on Crystal Growth and Crystal Technologies	1
Fundamentals of Crystallization	
Ab initio-based approach to elemental growth process on the InAs wetting layer grown on GaAs substrate T. Ito, K. Ogasawara, T. Sugitani, T. Akiyama and K. Nakamura	2
Change in the branch period of the step pattern formed by a moving linear source—initial coarsening and effect of an abrupt change in the velocity S. Kondo, M. Kawaguchi, M. Sato and M. Uwaha	6
Multiple-to-dominant path collapse of linked-flux model for diffusion-limited nucleation Y.H. Lau and D.T. Wu	13
On the growth mechanism of polycrystalline silicon thin film by Al-induced layer exchange process N. Usami, M. Jung and T. Suemasu	16
The effect of interfacial kinetics on the morphological stability of a spherical particle M.-W. Chen, X.-F. Wang, F. Wang, G.-B. Lin and Z.-Z. Wang	20
Influence of growth ambience and doping on the structural properties of multiferroic DyMnO ₃ H.S. Nair and S. Elizabeth	24
Ab initio-based approach to elemental nitridation process of α -Al ₂ O ₃ Y. Saito, T. Akiyama, K. Nakamura and T. Ito	29
Microstructure of diphase dendrite in Al–35%La alloy during solidification Y.H. Zheng, Z.D. Wang and S.M. Zhang	33
Optimization of silicon crystallization in a Bridgman growth furnace by numerical modeling M.P. Bellmann, H. Dalaker, M. Syvertsen, S. Gouttebroze and M. M'Hamdi	38
Structural stability and electronic properties in Al ₂ O ₃ –Cr ₂ O ₃ mixed crystal Y. Kitaoka, K. Nakamura, T. Akiyama and T. Ito	42
Three-dimensional simulation and experiment on micro-floating zone of LHPG with asymmetrical perturbation C.-Y. Lo and P.-Y. Chen	45
Crystallization kinetics and characterization of nanosized Nd:YAG by a modified sol–gel combustion process H. Gong, D.-Y. Tang, H. Huang, M.-D. Han, T. Sun, J. Zhang, X.-p. Qin and J. Ma	52
Microstructure evolution in Cu–1.54 wt% Cr alloy during directional solidification Z.P. Que, J.H. Lee, H.M. Jung, J.H. Shin, S.Z. Han and K.J. Euh	58
A simple anisotropic surface free energy function for three-dimensional phase field modeling of multi-crystalline crystal growth H.K. Lin, C.C. Chen and C.W. Lan	62
Growth and dissolution kinetics of a and c polymorphs of dl-methionine L. Wantha and A.E. Flood	66

Ultrasonic crystallization monitoring technique for simultaneous in-line measurement of liquid and solid phase T. Stelzer, D. Pertig and J. Ulrich	71
Analysis of W-shape melt/crystal interface formation in Czochralski silicon crystal growth O.A. Noghabi, M. Jomâa and M. M'hamdi	77
3D modelling of stresses and deformations during crystallisation of silicon accounting for ingot-crucible interactions M. M'Hamdi, S. Gouttebroze and H.G. Fjær	83
Crystal growth rates and optical resolution of dl-methionine hydrochloride by preferential crystallization from aqueous solution W. Srimahaprom and A.E. Flood	88
Effect of flow pattern on the segregation of impurities in vertical Bridgman growth of multi-crystalline silicon M.P. Bellmann and M. M'Hamdi	93
Comparative numerical study of the effects of rotating and traveling magnetic fields on the carbon transport in the solution growth of SiC crystals F. Mercier and S.-i. Nishizawa	99
Nucleation of Si and Ge by rapid cooling using molecular-dynamics simulation Y. Xiao, T. Motooka, R. Teranishi and S. Munetoh	103
Phase field modeling of crystal growth with nonlinear kinetics S.H. Liu, C.C. Chen and C.W. Lan	106
Synthesis and growth mechanism of tubular $\text{YAl}_3(\text{BO}_3)_4$ crystals in millimeter diameter Z. Cao, X. Yu, Y. Yue and Z. Hu	111
Crystal Growth and Various Technologies	
Crystallization in $\text{Na}_2\text{O}-\text{Nb}_2\text{O}_5-\text{Al}_2\text{O}_3-\text{SiO}_2$ glass-ceramics system with partial replacement of SnO_2 for Al_2O_3 P. Kongputhon, A. Niyompan and R. Tipakontitkul	116
Bridgman growth and characterization of $\text{Bi}_4(\text{Ge}_x\text{Si}_{1-x})_3\text{O}_{12}$ mixed crystals Y. Zhang, J. Xu, Q. He and B. Lu	121
Synthesis and growth of ZnGeP_2 crystals: Prevention of non-stoichiometry J. Cheng, S. Zhu, B. Zhao, B. Chen, Z. He, Q. Fan and T. Xu	125
Growth and physical properties of a new crystal for NLO applications: Bisguanidinium hydrogen phosphate monohydrate (G2HP) K. Russel Raj and P. Murugakoothan	130
Control of polymorphism in the anti-solvent crystallization with a particular temperature profile T. Minamisono and H. Takiyama	135
Germanium-doped crystalline silicon: A new substrate for photovoltaic application D. Yang, P. Wang, X. Yu and D. Que	140
Growth of Ce-doped $\text{Ba}_3\text{Gd}(\text{BO}_3)_3$ and $\text{Sr}_3\text{Gd}(\text{BO}_3)_3$ single crystals by micro-pulling-down method and analysis of luminescence properties R. Simura, T. Yagi, K. Sugiyama, T. Yanagida and A. Yoshikawa	145
Liquid-phase explosive crystallization of electron-beam-evaporated a-Si films induced by flash lamp annealing K. Ohdaira and H. Matsumura	149
Synthesis and physical properties of $\text{Li}_7\text{V}_{0.5}\text{Mn}_{0.5}\text{N}_4$ Y. Suzuki, Y. Inoue, K. Kuriyama and K. Kushida	153

Crystal growth and luminescence properties of Cr-doped YAlO ₃ single crystals M. Sugiyama, T. Yanagida, D. Totsuka, Y. Yokota, Y. Futami, Y. Fujimoto and A. Yoshikawa	157
Salts of amino acids with hexafluorosilicate anion V.V. Ghazaryan, M. Fleck and A.M. Petrosyan	162
Micro-pulling down method-grown Er ³⁺ :LiCaAlF ₆ as prospective vacuum ultraviolet laser material M. Cadatal-Raduban, T. Shimizu, K. Yamanoi, K. Takeda, M. Hong Pham, T. Nakazato, N. Sarukura, N. Kawaguchi, K. Fukuda, T. Suyama, T. Yanagida, Y. Yokota and A. Yoshikawa	167
Epitaxial growth of SiC with chlorinated precursors on different off-angle substrates S. Leone, A. Henry, E. Janzén and S. Nishizawa	170
Synthesis and characterisation of Copper Zinc Tin Sulphide (CZTS) compound for absorber material in solar-cells V. Kheraj, K.K. Patel, S.J. Patel and D.V. Shah	174
Growth and scintillation properties of Nd-doped Lu ₃ Al ₅ O ₁₂ single crystals by Czochralski and micro-pulling-down methods M. Sugiyama, Y. Fujimoto, T. Yanagida, A. Yamaji, Y. Yokota and A. Yoshikawa	178
Mixed salts of amino acids with different anions V.V. Ghazaryan, M. Fleck and A.M. Petrosyan	182
Growth of neodymium lanthanum calcium borate (NdLCB) single crystals by the Czochralski method and its characterisation M. Senthilkumar, M. Kalidasan, S. Sugan and R. Dhanasekaran	189
The study of rapid thermal annealing on arsenic-doped ZnO for the p-type ZnO formation Y.J. Chen, H.-W. Jen, M.-S. Wong, C.-H. Ho, J.-H. Liang, J.-T. Liu and J.-H. Pang	193
Effect of rapid thermal annealing on behavior of nitrogen in GaAsN alloys X.Z. Chen, D.H. Zhang, Y.J. Jin, J.H. Li, J.H. Teng and N. Yakovlev	197
Crystal growth of lanthanum calcium borate (LCB) single crystals from melt and its characterization M. Senthilkumar, M. Kalidasan, Sugan and R. Dhanasekaran	202
A simple approach to the polytypism in SiC T. Ito, T. Akiyama and K. Nakamura	207
Effect of N ⁵⁺ ion implantation in CVT grown ZnSe single crystals P. Kannappan, J.B.M. Krishna, G.S. Taki and R. Dhanasekaran	211
Crystal growth and characterization of the rare earth orthoferrite PrFeO ₃ X. Wang, S. Cao, Y. Wang, S. Yuan, B. Kang, A. Wu and J. Zhang	216
Unidirectional growth, improved structural perfection and physical properties of a semi-organic nonlinear optical dichlorobis(L-proline)zinc(II) single crystal U. Charoen-In, P. Ramasamy and P. Manyum	220
Floating zone growth and anisotropic magnetic properties of Pr _{1/2+y} Sr _{1/2-y} MnO ₃ single crystal B. Kang, S. Cao, X. Wang, S. Yuan, X. Qin and J. Zhang	227
Epitaxial growth of self-ordered ZnO nanostructures on sapphire substrates by seed-assisted hydrothermal growth H.-G. Chen, H.-D. Lian, S.-P. Hung and C.-F. Wang	231
Crystalline coats or hollow crystals as tools for product design in pharmaceutical industry J. Ulrich, A. Schuster and T. Stelzer	235
Selective epitaxial growth of GaAs by current controlled liquid phase epitaxy D. Mouleeswaran, T. Koyama, A. Tanaka and Y. Hayakawa	238

The control of mean ionic radius at Y site by Lu co-doping for Ce:LiYF ₄ single crystals Y. Yokota, A. Yamaji, T. Yanagida, N. Kawaguchi, K. Fukuda and A. Yoshikawa	243
Characterization of Crystals	
Fabrication and characterization of textured Bi ₂ Te ₃ thermoelectric thin films prepared on glass substrates at room temperature using pulsed laser deposition Z. Yu, X. Wang, Y. Du, S. Aminorroaya-Yamni, C. Zhang, K. Chuang and S. Li	247
Crystal growth and physical characterization of picolinic acid cocrystallized with dicarboxylic acids W. Somphon and K.J. Haller	252
Synthesis, growth and characterisation of tetrathiourea cadmium tetrathiocyanato zincate single crystals G. Pabitha and R. Dhanasekaran	259
Optical properties of hydrothermal-method-grown ZnO crystal as EUV laser diagnostics material K. Yamanoi, T. Shimizu, Y. Furukawa, M. Cadatal-Raduban, T. Nakazato, K. Sakai, M. Tsuboi, R. Nishi, N. Sarukura, M. Tanaka, M. Nishikino, H. Yamatani, K. Nagashima, T. Kimura, T. Fukuda, M. Nagasono, T. Togashi, A. Higashiya, M. Yabashi, T. Ishikawa, H. Ohashi and H. Kimura	264
Band gap energies of Li _{2x} Mg _(1-x) O materials synthesized by the sol–gel method N.F. Chayed, N. Badar, R. Rusdi, A. Azahidi and N. Kamarulzaman	268
Growth, properties and first-principles study of mid-IR nonlinear optical crystal LiInS ₂ S. Wang, H. Ruan, G. Liu, G. Zhang, Q. Shi, X. Zhang, Z. Gao, C. Dong and X. Tao	271
Formation of compressively strained Si/Si _{1-x} C _x /Si(100) heterostructures using gas-source molecular beam epitaxy K. Arimoto, H. Furukawa, J. Yamanaka, C. Yamamoto, K. Nakagawa, N. Usami, K. Sawano and Y. Shiraki	276
Formation of compressively strained SiGe/Si(110) heterostructures and their characterization K. Arimoto, T. Obata, H. Furukawa, J. Yamanaka, K. Nakagawa, K. Sawano and Y. Shiraki	282
Pr or Ce-doped, fast-response and low-afterglow cross-section-enhanced scintillator with ⁶ Li for down-scattered neutron originated from laser fusion K. Watanabe, Y. Arikawa, K. Yamanoi, M. Cadatal-Raduban, T. Nagai, M. Kouno, K. Sakai, T. Nazakato, T. Shimizu, N. Sarukura, M. Nakai, T. Norimatsu, H. Azechi, A. Yoshikawa, T. Murata, S. Fujino, H. Yoshida, N. Izumi, N. Satoh and H. Kan	288
Effect of thermal annealing on the optical properties of CdGeAs ₂ wafers W. Huang, B. Zhao, S. Zhu, Z. He, B. Chen, J. Li, Y. Yu, J. Tang and W. Liu	291
Valence state of dopant and scintillation properties of Ce-doped Sr ₃ Y(BO ₃) ₃ crystal R. Simura, S. Kawai, K. Sugiyama, T. Yanagida, T. Sugawara, T. Shishido and A. Yoshikawa	296
The local generation and recombination lifetime based on forward diode characteristics diagnostics W. Pengchan, T. Phetchakul and A. Poyai	300
Studies on growth, spectral and mechanical properties of new organic NLO crystal: Guanidinium 4-nitrobenzoate (GuNB) T. Arumanayagam and P. Murugakoothan	304
Crystal growth and piezoelectric, elastic and dielectric properties of novel LiInS ₂ crystal S. Wang, Z. Gao, X. Yin, G. Liu, H. Ruan, G. Zhang, Q. Shi, C. Dong and X. Tao	308
Impact of diameter fluctuations on thermal stresses during Czochralski silicon growth O.A. Noghabi, M. M'Hamdi and M. Jomâa	312
Growth, vibrational and luminescence analysis of monoclinic KGd _(1-x) Pr _x (WO ₄) ₂ ($x=0.005, 0.02, 0.05$) single crystals D. Thangaraju, S. Moorthy Babu, A. Durairajan, D. Balaji, P. Samuel and Y. Hayakawa	319

Structural stability of Mn-doped GaInAs and GaInN alloys M. Miyake, K. Nakamura, T. Akiyama and T. Ito	324
Bridgman growth and defect characterization of large diameter mercury indium telluride crystals for near infrared detectors L. Wang and W. Jie	327
<i>In vitro</i> crystallization, characterization and growth-inhibition study of urinary type struvite crystals C.K. Chauhan and M.J. Joshi	330
Growth of ADP-KDP mixed crystal and its optical, mechanical, dielectric, piezoelectric and laser damage threshold studies P. Rajesh, P. Ramasamy and G. Bhagavannarayana	338
Effect of rare earth ions on the properties of glycine phosphite single crystals K. Senthilkumar, S. Moorthy Babu, B. Kumar and G. Bhagavannarayana	343
Melt growth, characterization and properties of bulk In_2O_3 single crystals Z. Galazka, R. Uecker, K. Irmscher, D. Schulz, D. Klimm, M. Albrecht, M. Pietsch, S. Ganschow, A. Kwasniewski and R. Fornari	349
Optical and structural studies of InN/GaN dots with varying GaN cap thickness W.-C. Ke, C.-Y. Kao, W.-C. Houng and C.-A. Wei	353